## NSN 5961-00-868-4320

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-868-4320 **Inclosure Material:** Glass **Overall Length:** Between 0.250 inches and 0.290 inches **Terminal Length:** Between 1.400 inches and 1.600 inches **Overall Diameter:** Between 0.090 inches and 0.110 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 18.0 reverse voltage, dc **Current Rating Per Characteristic:** 10.00 amperes source cutoff current universal **Power Rating Per Characteristic:** 150.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 80131-release3881 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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